

Power Factor and PWM Controller

FEATURES

- PFC and PWM Single Chip Solution
- Synchronized Operation up to 300kHz
- 99% Power Factor over 20:1 Load Current Range
- Current Mode PWM
- Instantaneous Overvoltage Protection
- Dedicated Overvoltage Protection (OVP Pin)
- Minimal Line Current Dead Zone
- Typical 250µA Start-Up Supply Current
- Line Switching Noise Filter
- Low Quiescent Current: 13mA
- Fast 2A Peak Current Gate Drivers
- Separate Soft Start Controls

APPLICATIONS

 Universal Power Factor Corrected Power Supplies and Preregulators

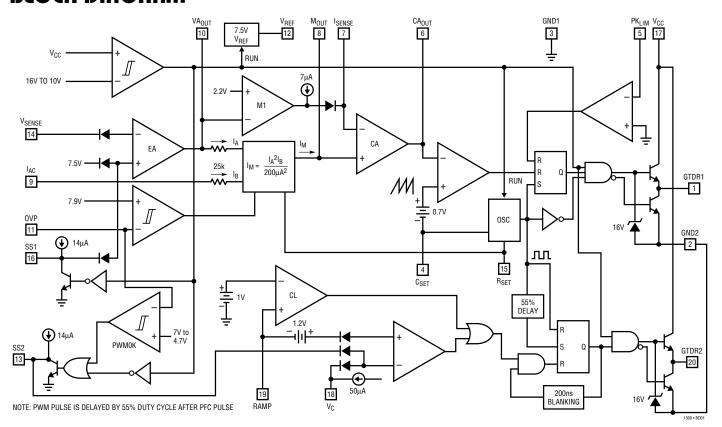
DESCRIPTION

The LT®1509 is a complete solution for universal off-line switching power supplies utilizing active power factor correction. The PFC section is identical to the LT1248 PFC controller except the EN/SYNC pin is removed because PFC and PWM are synchronized internally.

The current mode PWM section (the LT1508 is the voltage-mode counterpart) contains all the primary side functions to convert the PFC preregulated high voltage output to an isolated low voltage output. The PWM duty cycle is internally limited to 47% (maximum 50%) to prevent transformer saturation. PWM soft start begins when PFC output reaches the preset voltage. In the event of brief line loss, the PWM will be shut off when the PFC output voltage drops below 73% of the preset value.

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BLOCK DIAGRAM



DESCRIPTION

By using fixed high frequency PWM current averaging without the need for slope compensation, the LT1509 achieves far lower line current distortion with a smaller magnetic element than systems that use either peak current detection, or zero current switching approach, in both continuous and discontinuous modes of operation.

The LT1509 also provides filtering capability to reject line switching noise which can cause instability when fed into

the multiplier. Line current dead zone is minimized with low bias voltage at the current input to the multiplier.

The LT1509 provides many protection features including peak current limiting and overvoltage protection. Implemented with a very high speed process, the LT1509 can be operated at frequencies as high as 300kHz.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	
GTDR Current Continuous	0.5A
GTDR Output Energy	5µJ
I _{AC} , R _{SET} , PK _{LIM} Input Current	20mA
V _{SENSE} , OVP Input Voltage	. V _{MAX}
RAMP, V _C Input Voltage	8V
I _{SENSE} , M _{OUT} Input Current	
Operating Junction Temperature Range	
Commercial0°C to	100°C
Industrial –40°C to	125°C
Thermal Resistance (Junction-to-Ambient)	
N Package10	0°C/W
SW Package12	

PACKAGE/ORDER INFORMATION

GTDR1 1	TOP VIEW 20 GTDR2	ORDER PART NUMBER
	19 RAMP 18 V _C 17 V _{CC} 16 SS1 15 R _{SET} 14 V _{SENSE} 13 SS2 12 V _{REF} 11 OVP SW PACKAGE 20-LEAD PLASTIC SO WIDE 125°C, θ _{JA} = 100°C/W (N) 125°C, θ _{JA} = 120°C/W (SW)	LT1509CN LT1509CSW LT1509IN LT1509ISW

Consult factory for Military grade parts.

ELECTRICAL CHARACTERISTICS

Maximum operating voltage (V_{MAX}) = 25V, V_{CC} = 18V, R_{SET} = 15k to GND, C_{SET} = 1nF to GND, I_{AC} = 100 μ A, I_{SENSE} = 0V, CA_{OUT} = 3.5V, VA_{OUT} = 5V, OVP = V_{REF} . No load on any outputs unless otherwise noted.

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Overall			•			
Supply Current (V _{CC} in Undervoltage Lockout)	V _{CC} = Lockout Voltage -0.2V	•		0.25	0.45	mA
Supply Current On	$11.5V \le V_{CC} \le V_{MAX}$	•		13	19	mA
V _{CC} Turn-On Threshold (Undervoltage Lockout)		•	15.5	16.5	17.5	V
V _{CC} Turn-Off Threshold		•	9.5	10.5	11.5	V
Voltage Amplifier (PFC Section)						
Voltage Amp Offset	VA _{OUT} = 3.5V	•	- 10		10	mV
Input Bias Current	V _{SENSE} = 0V to 7V	•		-25	-250	nA
Voltage Gain			70	100		dB
Voltage Amp Unity-Gain Bandwidth				3		MHz
Voltage Amp Output High (Internally Clamped)		•	11.3	13.3		V
Voltage Amp Output Low		•		1.1	2	V
Voltage Amp Short-Circuit Current	VA _{OUT} = 0V	•	3	8	17	mA

ELECTRICAL CHARACTERISTICS Maximum operating voltage (V_{MAX}) = 25V, V_{CC} = 18V, R_{SET} = 15k to GND, C_{SET} = 1nF to GND, I_{AC} = 100 μ A, I_{SENSE} = 0V, CA_{OUT} = 3.5V, VA_{OUT} = 5V, OVP = V_{REF} . No load on any outputs unless otherwise noted.

Current Amplifier (PFC Section) ±1 ±4 mV Current Amp Offset Voltage • ±1 ±4 mV Series Blas Current • −25 −250 nA Current Amp Voltage Gain 80 110 dB Current Amp Output High • 7.2 8.5 V Current Amp Output High • 7.3 8.5 V Current Amp Output High • 7.3 8.5 V Current Amp Output High • 0.03 1 V Current Amp Output Lind Carrent Amplies	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
SENSE Bias Current	Current Amplifier (PFC Section)		•			
Current Amp Voltage Gain 80 110 dB Current Amp Unity-Gain Bandwidth • 7.2 8.5 VMHz Current Amp Dutput High • 7.2 8.5 V Current Amp Dutput Low • 1.1 2 V Current Amp Short-Circuit Current CA _{OUT} = OV • 3 8 17 mA Bright Fange, Espase, Mour (Linear Operation) • -0.3 1 V V 7.39 7.50 7.60 V Reference Reference Output Voltage I.REF = 0MA, TA = 25°C 7.39 7.50 7.60 V Vege Load Regulation -1.5MA < I.REF = 0MA	Current Amp Offset Voltage		•	±1	±4	mV
Current Amp Unity-Gain Bandwidth ■ 7.2 8.5 V Current Amp Output High ■ 7.2 8.5 V Current Amp Output Living ■ 1.1 2 V Current Amp Short-Circuit Current CA _{OUT} = OV ■ 3 8 17 mA Input Range, Issaiss, Mour Cliniar Operation) Reference — -0.3 1 V Reference Output Voltage I _{REF} = OmA, T _A = 25°C 7.39 7.50 7.50 7.60 V V _{REF} Line Regulation — -5mA < I _{REF} < OmA	I _{SENSE} Bias Current		•	-25	-250	nA
Current Amp Output High ● 7.2 8.5 V Current Amp Output Low ● 1.1 2 V Current Amp Output Low ● 3.8 17 mA Input Range, Isense, Moutr (Linear Operation) ● -0.3 1 V Reference V -0.3 1 V Reference Output Voltage Inger = 0mA, TA = 25°C 7.39 7.50 7.60 V Vegr Load Regulation -5mA < Inger < 0mA	Current Amp Voltage Gain		80	110		dB
Current Amp Output Low ■ 1.1.1 2 V Current Amp Short-Circuit Current Input Range, Issags, Mourt (Linear Operation) ■ 3.8 1.7 mA Reference Reference Vage Load Regulation -5mA x Isper omA 5 mV Vage Load Regulation -5mA x Isper omA 5 mV Vage Load Regulation 11.5V < Voc < VMAX	Current Amp Unity-Gain Bandwidth			3		MHz
Current Amp Short-Circuit Current CA _{OUT} = OV ● 3 8 17 mA Input Range, I _{SENSE} , MDIPUT (Linear Operation) Polary (Linear Operation) 1 V Reference Output Voltage I _{REF} = 0mA, T _A = 25°C 7.39 7.50 7.60 V Vage Land Regulation -5mA < I _{REF} < 0mA	Current Amp Output High		7.2	8.5		V
Input Range, Isense, Mour (Linear Operation) Meference	Current Amp Output Low		•	1.1	2	V
Reference Reference I _{REF} = 0mA, T _A = 25°°C 7.39 7.50 7.60 V Y _{REF} Load Regulation -5mA < I _{REF} < 0mA	Current Amp Short-Circuit Current	CA _{OUT} = 0V	3	8	17	mA
Reference Reference Output Voltage I _{REF} = 0mA, T _A = 25°C 7.39 7.50 7.60 V V _{REF} Load Regulation -5mA < I _{REF} = 0mA 5 mV V _{REF} Line Regulation 11.5V < V _{CC} < V _{MAX} • -20 5 20 mV V _{REF} Line Regulation 11.5V < V _{CC} < V _{MAX} • -20 5 20 mV V _{REF} Dont-Circuit Current V _{REF} = 0V • 12 28 50 mA V _{REF} Worst Case Load, Line, Temperature • 7.32 7.5 7.68 V Current Limit V V _{REF} Worst Case • -25 25 mV V _{REF} Worst Voltage • -25 25 mV V _{REMIN} TOSTOR Propagation Delay PK _{LIM} = 0.1V • -50 -100 µA V _{REMIN} TOSTOR Propagation Delay PK _{LIM} = 0.1V • -50 -100 mS Multiplier Output Current I _{AC} = 100µA, R _{SET} = 15k 0.00 0.00 mS Multiplier Output Current Offset R _{AC} = 1M from I _{AC} to GND • -2.66 -2.65 -2.5 µA Multiplier Output Current Offset R _{AC} = 1M from I _{AC} to GND • -2.66 -2.60 -2.35 µA Multiplier Maximum Output Current I _{AC} = 450µA, R _{SET} = 15k, V _{AQUT} = 7V, M _{QUT} = 0V • -2.86 -2.60 -2.35 µA Multiplier Gain Constant (Note 1) • 0.035 V U _{AC} Input Resistance I _{AC} from 50µA to 1mA 15 25 35 kΩ U _{AC} Oscillator S _{AC} = 15k, C _{SET} = 1000pF • 85 100 115 kHz R _{SET} = 15k, C _{SET} = 1500pF • 85 100 115 kHz R _{SET} = 15k, C _{SET} = 1500pF • 10 1.5 1.3 1.55 V U _{CEST} Ramp Peak-to-Peak Amplitude 4.35 4.7 5.0 V C _{SET} Ramp Valley Voltage 5 1.5 1.3 1.55 V U _{CEST} Ramp Valley Voltage 5 1.04 1.05 1.06 U _{CEST} Ramp Valley Voltage 5 1.04 1.05 1.06 U _{CEST} Ramp Valley Voltage 5 1.04 1.05 1.06 U _{CEST} Ramp Valley Voltage 5 1.04 1.05 1.06 U _{CEST} Ramp Valley Voltage 5 1.05 1.07 V U _{CEST} Ramp Valley Voltage 5 1.05 1.07 V U _{CEST} Ramp Valley Voltage 5 1.05 1.07 V U _{CEST} Ramp Valley Voltage 5 1.05 1.07 V U _{CEST} Ramp Valley Voltage 5 1.05 1.07 V U _{CEST} Ramp Valley Voltage 5 1.05 1.07 V U _{CEST} Ram	Input Range, I _{SENSE} , M _{OUT} (Linear Operation)		-0.3		1	V
Varier Load Regulation −5mA < I _{REF} < 0mA 5 mV Varier Line Regulation 11.5V < V _{DC} < V _{MAX} • −20 5 20 mV Varier Short-Circuit Current V _{REF} OV • 12 28 50 mA Varier Short-Circuit Current V _{REF} OV • 12 28 50 mA Varier Short-Circuit Current V _{REF} OV • 12 28 50 mA Walter Short Circuit Current Limit PK _{LIM} Digital Current PK _{LIM} = 0.1V • 0 −25 25 mV PK _{LIM} bot GTDR Propagation Delay PK _{LIM} Falling from 50mV to −50mV 400 ns ms Multiplier Output Current I AC = 100µA, R _{SET} = 15k 35 µA Multiplier Output Current I AC = 100µA, R _{SET} = 15k 35 µA Multiplier Output Current I AC = 100µA, R _{SET} = 15k 0.03 0.035 V Multiplier Gain Constant (Note 1) I AC = 450µA, R _{SET} = 15k V _{AU} = 7.0 0.035 V Multiplier Gain Constan	Reference					
VREF Line Regulation 11.5V < V _{CC} < V _{MAX} ● −20 5 20 mV VREF Stort-Circuit Current VREF = OV ● 12 28 50 mA VREF Worst Case Load, Line, Temperature ● 7.32 7.5 7.68 V Current Limit PK _{LIM} Offset Voltage ● −25 25 mV PK _{LIM} Ippt Current PK _{LIM} Falling from 50mV to −50mV 400 ns Multiplier Multiplier Output Current I.ac = 100µA, RSET = 15k 35 µA Multiplier Output Current Offset Rac = 1M from Iac to GND ● −0.05 −0.5 µA Multiplier Gain Constant (Note 1) Iac = 450µA, RSET = 15k, VA _{OUT} = 7V, M _{OUT} = 0V ● −286 −260 −235 µA Multiplier Gain Constant (Note 1) Iac = 450µA, RSET = 15k, VA _{OUT} = 7V, M _{OUT} = 0V ● −286 −260 −235 µA Multiplier Gain Constant (Note 1) Iac = 15k, CSET = 15k,	Reference Output Voltage	I _{REF} = 0mA, T _A = 25°C	7.39	7.50	7.60	V
VREF Line Regulation 11.5V < V _{CC} < V _{MAX} ● −20 5 20 mV VREF Stort-Circuit Current VREF = OV ● 12 28 50 mA VREF Worst Case Load, Line, Temperature ● 7.32 7.5 7.68 V Current Limit PK _{LIM} Offset Voltage ● −25 25 mV PK _{LIM} Ippt Current PK _{LIM} Falling from 50mV to −50mV 400 ns Multiplier Multiplier Output Current I.ac = 100µA, RSET = 15k 35 µA Multiplier Output Current Offset Rac = 1M from Iac to GND ● −0.05 −0.5 µA Multiplier Gain Constant (Note 1) Iac = 450µA, RSET = 15k, VA _{OUT} = 7V, M _{OUT} = 0V ● −286 −260 −235 µA Multiplier Gain Constant (Note 1) Iac = 450µA, RSET = 15k, VA _{OUT} = 7V, M _{OUT} = 0V ● −286 −260 −235 µA Multiplier Gain Constant (Note 1) Iac = 15k, CSET = 15k,	V _{REF} Load Regulation			5		mV
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VREF Worst Case Load, Line, Temperature • 7.32 7.5 7.68 V Current Limit PK _{LIM} Offset Voltage • −25 25 mV PK _{LIM} 10 GTDR Propagation Delay PK _{LIM} Falling from 50mV to −50mV 400 ns Multiplier Multiplier Output Current I _{AC} = 100μA, R _{SET} = 15k 35 μA Multiplier Output Current Offset R _{AC} = 1M from I _{AC} to GND • −0.05 −0.5 μA Multiplier Gain Constant (Note 1) I _{AC} = 450μA, R _{SET} = 15k, VA _{OUT} = 7V, M _{OUT} = 0V • −286 −260 −235 μA Multiplier Gain Constant (Note 1) I _{AC} from 50μA to 1mA 15 25 35 kΩ Oscillator Oscillator Frequency R _{SET} = 15k, C _{SET} = 1000pF • 85 100 115 kHz Seg Ramp Peak-to-Peak Amplitude • 85 100 115 kHz Ceg Ramp Valley Voltage • 1.15 1.3 1.55 V Overvoltage Comparator (PFC Section) • 1.04 1.05 1.06 +			12	28	50	mA
Current Limit PK _{LIM} Offset Voltage ● −25 25 mV PK _{LIM} Input Current PK _{LIM} = −0.1V ● −25 −25 mV PK _{LIM} for GTDR Propagation Delay PK _{LIM} Falling from 50mV to −50mV 400 ns Multiplier Multiplier Output Current I _{AC} = 100µA, R _{SET} = 15k 35 µA Multiplier Output Current Offset R _{AC} = 1M from I _{AC} to GND ● −0.05 −0.5 µA Multiplier Gain Constant (Note 1) I _{AC} = 450µA, R _{SET} = 15k, VA _{OUT} = 7V, M _{OUT} = 0V ● −286 −260 −235 µA Multiplier Gain Constant (Note 1) 0.035 V⁻ I _{AC} Input Resistance I _{AC} from 50µA to 1mA 15 25 35 kΩ Oscillator RSET = 15k, C _{SET} = 1500pF ● 85 100 115 kHz CSET Ramp Peak-to-Peak Amplitude RSET = 15k, C _{SET} = 1500pF ● 85 68 78 kHz CSET Ramp Valley Voltage 1.15 1.3 1.55 V Overvoltage Comparator (PFC Section) 0.03 0.03 V Comparator Trip			7.32	7.5	7.68	V
PK _{LIM} Input Current PK _{LIM} = 0.1V ■ 50 −100 μA PK _{LIM} to GTDR Propagation Delay PK _{LIM} Falling from 50mV to −50mV 400 ns Multiplier Name Author ns Multiplier Output Current I _{AC} = 100μA, R _{SET} = 15k 35 μA Multiplier Output Current Offset R _{AC} = 1M from I _{AC} to GND ■ −0.05 −0.5 μA Multiplier Gain Constant (Note 1) I _{AC} = 450μA, R _{SET} = 15k, VA _{OUT} = 7V, M _{OUT} = 0V ■ −286 −260 −235 μA Multiplier Gain Constant (Note 1) I _{AC} from 50μA to 1mA 15 25 35 kΩ Oscillator Voscillator Voscillator Voscillator Voscillator Voscillator Oscillator Frequency R _{SET} = 15k, C _{SET} = 1000pF ● 85 100 115 kHz C _{SET} Ramp Peak-to-Peak Amplitude Past = 15k, C _{SET} = 1500pF ● 85 68 78 kHz C _{SET} Ramp Valley Voltage 1.15 1.3 1.55 V Overvoltage Comparator (PFC Section) Overvoltage Comparator (PFC Section) Ins <td></td> <td></td> <td></td> <td></td> <td></td> <td></td>						
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PK _{LIM} to GTDR Propagation Delay PK _{LIM} Falling from 50mV to −50mV 400 ns Multiplier Multiplier Output Current I _{AC} = 100µA, R _{SET} = 15k 35 µA Multiplier Output Current Offset R _{AC} = 1M from I _{AC} to GND • −286 −260 −235 µA Multiplier Gain Constant (Note 1) 0.035 V⁻² I _{AC} Input Resistance I _{AC} from 50µA to 1mA 15 25 35 kΩ Oscillator RSET = 15k, C _{SET} = 1000pF • 85 100 115 kHz CSET Ramp Peak-to-Peak Amplitude 4.35 4.7 5.0 V CSET Ramp Valley Voltage 1.15 1.3 1.55 V Overvoltage Comparator (PFC Section) 0 0.335 V Owproltage Comparator (PFC Section) 0 0.35 V Overposation Delay 0 1.04 1.05 1.06 Hysteresis 0 0.2 1 µA OVP Propagation Delay 0 0.2 1 µA OVP Propagation Delay 0 <td></td> <td>$PK_{LIM} = -0.1V$</td> <td></td> <td>-50</td> <td></td> <td></td>		$PK_{LIM} = -0.1V$		-50		
Multiplier Multiplier Output Current I _{AC} = 100μA, R _{SET} = 15k 35 μA Multiplier Output Current Offset R _{AC} = 1M from I _{AC} to GND • -0.05 -0.05 -0.5 μA Multiplier Gain Constant (Note 1) I _{AC} = 450μA, R _{SET} = 15k, VA _{OUT} = 7V, M _{OUT} = 0V • -286 -260 -235 μA Multiplier Gain Constant (Note 1) I _{AC} from 50μA to 1mA 15 25 35 kΩ I _{AC} Input Resistance I _{AC} from 50μA to 1mA 15 25 35 kΩ Oscillator Oscillator Frequency R _{SET} = 15k, C _{SET} = 1000pF • 85 100 115 kHz R _{SET} = 15k, C _{SET} = 1500pF • 85 68 78 kHz C _{SET} Ramp Peak-to-Peak Amplitude 4.35 4.7 5.0 V C _{SET} Ramp Valley Voltage 1.15 1.3 1.55 V Overvoltage Comparator (PFC Section) Comparator (PFC Section) Comparator Trip Voltage Ratio (V _{TRIP} /V _{REF}) • 1.04 1.05 1.06 </td <td></td> <td>=</td> <td></td> <td></td> <td></td> <td></td>		=				
Multiplier Output Current I _{AC} = 100μA, R _{SET} = 15k 35 μΔ Multiplier Output Current Offset R _{AC} = 1M from I _{AC} to GND • -0.05 -0.5 μΔ Multiplier Maximum Output Current I _{AC} = 450μA, R _{SET} = 15k, VA _{OUT} = 7V, M _{OUT} = 0V • -286 -260 -235 μΔ Multiplier Gain Constant (Note 1) 0.035 V⁻² 1 0.035 V⁻² I _{AC} Input Resistance I _{AC} from 50μA to 1mA 15 25 35 kΩ Oscillator **Oscillator Oscillator Frequency R _{SET} = 15k, C _{SET} = 1000pF • 85 100 115 kHz C _{SET} Ramp Peak-to-Peak Amplitude 4.35 4.7 5.0 V C _{SET} Ramp Valley Voltage 1.15 1.3 1.55 V Overvoltage Comparator (PFC Section) **Comparator (PFC Section) Comparator Trip Voltage Ratio (V _{TRIP} /V _{REF}) • 1.04 1.05 1.06 ** Hysteresis 0.07 0.02 1 μΑ OVP Propagation Delay • 0.2 1 μΑ<		The Link Committee of the Committee of t				
Multiplier Output Current Offset R_{AC} = 1M from I_{AC} to GND −0.05 −0.05 −0.5 μA Multiplier Maximum Output Current I_{AC} = 450μA, R_{SET} = 15k, VA_{OUT} = 7V, V_{OUT} = 0V −286 −260 −235 μA Multiplier Gain Constant (Note 1) 0.035 V ^{−2} I_{AC} Input Resistance I_{AC} from 50μA to 1mA 15 25 35 V_{C} Oscillator Oscillator Frequency R _{SET} = 15k, C _{SET} = 1000pF 85 100 115 kHz C _{SET} Ramp Peak-to-Peak Amplitude 8.5 100 115 kHz C _{SET} Ramp Valley Voltage 9.1.15 1.33 1.55 V Overvoltage Comparator (PFC Section) Comparator Trip Voltage Ratio (V _{TRIP} /V _{REF}) 9.1.04 1.05 1.06 +1.04 1.05 1.06 +1.04 1.05 1.06 +1.04 1.05 1.06 +1.04 1.05 1.06 +1.04 1.05 1.06 +1.04 1.05 1.06 +1.04 1.05 1.06 +1.0		IAC = 100uA, RSFT = 15k		35		uΑ
Multiplier Maximum Output Current I _{AC} = 450μA, R _{SET} = 15k, VA _{OUT} = 7V, M _{OUT} = 0V -286 -260 -235 μΔ Multiplier Gain Constant (Note 1) I _{AC} from 50μA to 1mA 15 25 35 kΩ Oscillator Oscillator Frequency R _{SET} = 15k, C _{SET} = 1000pF • 85 100 115 kHz C _{SET} Ramp Peak-to-Peak Amplitude 4.35 4.7 5.0 V C _{SET} Ramp Valley Voltage 1.15 1.3 1.55 V Overvoltage Comparator (PFC Section) Comparator Trip Voltage Ratio (V _{TRIP} /V _{REF}) • 1.04 1.05 1.06 Hysteresis 0.35 V OVP Propagation Delay • 0.2 1 μA OVP Propagation Delay • 0.2 1 μA Gate Drivers (GTDR1 and GTDR2) Max Output Voltage 0mA Load, 18V < V _{CC} • 12 15 17.5 V Output Low (Device Unpowered) V _{CC} = 0V,			•		-0.5	
Multiplier Gain Constant (Note 1) 0.035 V⁻²² I _{AC} Input Resistance I _{AC} from 50μA to 1mA 15 25 35 kΩ Oscillator Oscillator Frequency R _{SET} = 15k, C _{SET} = 1000pF R _{SET} = 1500pF ● 85 100 115 kHz C _{SET} Ramp Peak-to-Peak Amplitude 4.35 4.7 5.0 V C _{SET} Ramp Valley Voltage 1.15 1.3 1.55 V Overvoltage Comparator (PFC Section) Comparator Trip Voltage Ratio (V _{TRIP} /V _{REF}) ● 1.04 1.05 1.06 Hysteresis 0.35 V OVP Bias Current 0VP = 7.5V ● 0.2 1 μA OVP Propagation Delay 100 ns Gate Drivers (GTDR1 and GTDR2) Max Output Voltage 0mA Load, 18V < V _{CC} ● 12 15 17.5 V Output Low (Device Unpowered) V _{CC} = 0V, 50mA Load (Sinking) ● 0.9 1.5 V Output Low (Devic		1.0	-286			
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		1AG 100ps (1.13E) 1.01 (1.10) 1.1 (1.10)				V ⁻²
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		Iac from 50uA to 1mA	15		35	
Oscillator Frequency RSET = 15k, CSET = 1000PF RSET = 15k, CSET = 1500PF ● 85 100 58 68 78 kHz KHZ CSET Ramp Peak-to-Peak Amplitude 4.35 4.7 5.0 V V CSET Ramp Valley Voltage 1.15 1.3 1.55 V V Overvoltage Comparator (PFC Section) • 1.04 1.05 1.06 1.06 Hysteresis 0.35 V V OVP Bias Current 0VP = 7.5V • 0.2 1 μA OVP Propagation Delay 100 ns Gate Drivers (GTDR1 and GTDR2) Max Output Voltage 0mA Load, 18V < VCC • 12 15 17.5 V Output High -200mA Load, 11.5V ≤ VCC ≤ 15V • VCC - 3.0 V Output Low (Device Unpowered) VCC = 0V, 50mA Load (Sinking) • 0.5 1.0 V V Output Low (Device Active) 200mA Load (Sinking) • 0.5 1.0 V V Peak Output Current 10nF from GTDR to GND 25 ns ns Max Duty Cycle (PFC) 90 96 %		Au especial				
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		Rset = 15k. Cset = 1000pF	85	100	115	kHz
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$						
	C _{SET} Ramp Peak-to-Peak Amplitude		4.35	4.7	5.0	V
	C _{SFT} Ramp Valley Voltage		1.15	1.3	1.55	V
	_ =		ı			<u> </u>
Hysteresis0.35VOVP Bias Current0VP = 7.5V•0.21μAOVP Propagation Delay100nsGate Drivers (GTDR1 and GTDR2)Max Output Voltage0mA Load, 18V < V _{CC} •121517.5VOutput High−200mA Load, 11.5V ≤ V _{CC} ≤ 15V•V _{CC} − 3.0VOutput Low (Device Unpowered)V _{CC} = 0V, 50mA Load (Sinking)•0.91.5VOutput Low (Device Active)200mA Load (Sinking)•0.51.0VPeak Output Current10nF from GTDR to GND2ARise and Fall Time1nF from GTDR to GND25nsMax Duty Cycle (PFC)9096%	Comparator Trip Voltage Ratio (V _{TRIP} /V _{RFF})		1.04	1.05	1.06	
				0.35		V
		0VP = 7.5V	•	0.2	1	μА
	OVP Propagation Delay					
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$						
		0mA Load, 18V < V _{CC}	12	15	17.5	V
Output Low (Device Unpowered) V _{CC} = 0V, 50mA Load (Sinking) ● 0.9 1.5 V Output Low (Device Active) 200mA Load (Sinking) 10mA Load ● 0.5 1.0 V Peak Output Current 10nF from GTDR to GND 2 A Rise and Fall Time 1nF from GTDR to GND 25 ns Max Duty Cycle (PFC) 90 96 %	Output High		► V _{CC} – 3.0			V
Output Low (Device Active) 200mA Load (Sinking) 10mA Load ● 0.5 0.2 0.4 V Peak Output Current 10nF from GTDR to GND 2 A A Rise and Fall Time 1nF from GTDR to GND 25 ns Max Duty Cycle (PFC) 90 96 % %	Output Low (Device Unpowered)	***	• "	0.9	1.5	V
10mA Load ● 0.2 0.4 V Peak Output Current 10nF from GTDR to GND 2 A Rise and Fall Time 1nF from GTDR to GND 25 ns Max Duty Cycle (PFC) 90 96 %						
Rise and Fall Time 1nF from GTDR to GND 25 ns Max Duty Cycle (PFC) 90 96 %	,		•	0.2	0.4	V
Max Duty Cycle (PFC) 90 96 %	Peak Output Current	10nF from GTDR to GND		2		А
	Rise and Fall Time	1nF from GTDR to GND		25		ns
	Max Duty Cycle (PFC)		90	96		%
Max Duty Cycle (PWM) (Note 2) 44 50 %	Max Duty Cycle (PWM) (Note 2)		44		50	%



ELECTRICAL CHARACTERISTICS

 V_{CC} = 18V, R_{SET} = 15k to GND, C_{SET} = 1nF to GND, I_{AC} = 100 μ A, I_{SENSE} = 0V, CA_{OUT} = 3.5V, VA_{OUT} = 5V, OVP = V_{REF} . No load on any outputs, unless otherwise noted.

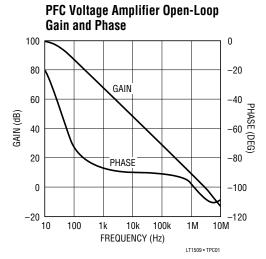
PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Soft Start Current	<u>'</u>					
SS1 Current (PFC)	SS1 = 2.5V	•	5	12	30	μА
SS2 Current (PWM)	SS2 = 1V	•	5	12	30	μΑ
Comparators in PWM Section	·					
RAMP Input Current	RAMP = $0V$, $V_C = 1.6V$	•		-0.3	-2	μΑ
Current Limit Comparator (CL) Threshold	V _C > 2.6V	•	0.95	1.1	1.2	V
GTDR2 Switching Off Threshold at V _C or at SS2	RAMP = 0V	•	1			V
V _C Input Current	V _C = 0V	•	-20		-80	μΑ
PWMOK Comparator Low Threshold (in Terms of V _{REF})		•	0.57	0.63	0.70	
V _C Pin High Voltage (LT1509)	1mA into V _C Pin	•	2.6	3.2	3.8	V
GTDR2 Turn-On Blanking Time				180		ns

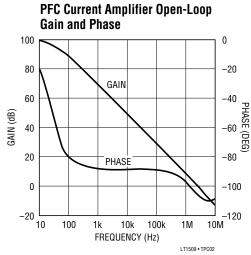
The ● denotes specifications which apply over the full operating temperature range.

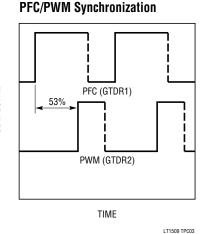
Note 1: Multiplier Gain Constant: $K = \frac{I_M}{I_{AC} (VA_{OUT} - 2)^2}$

Note 2: GTDR2 (PWM) pulse is delayed by 53% duty cycle after GTDR1 (PFC) is set. See PFC/PWM Synchronization graph in the Typical Performance Characteristics section.

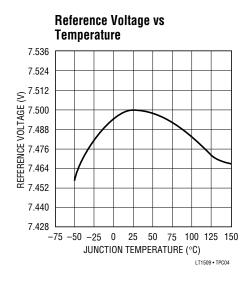
TYPICAL PERFORMANCE CHARACTERISTICS

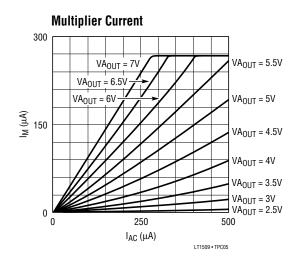


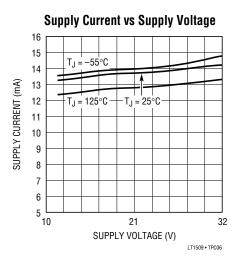


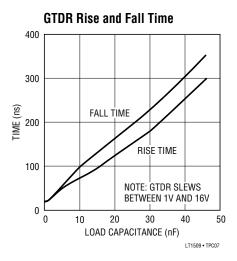


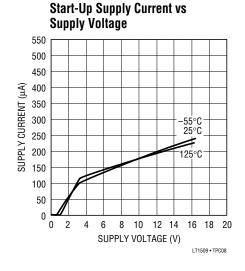
TYPICAL PERFORMANCE CHARACTERISTICS

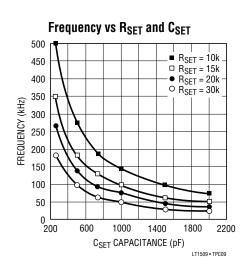


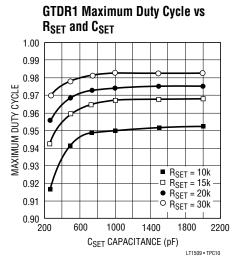


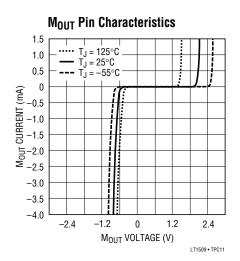






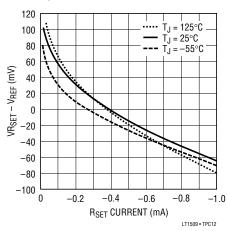




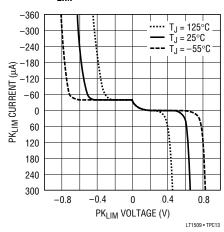


TYPICAL PERFORMANCE CHARACTERISTICS

R_{SET} Voltage vs Current



PK_{LIM} Pin Characteristics



PIN FUNCTIONS (For application help with the PFC portion of this chip, see the LT1248 data sheet)

PFC SECTION

GTDR1 (Pin 1): The PFC MOSFET gate driver is a fast totem pole output which is clamped at 15V. Capacitive loads like the MOSFET gates may cause overshoot. A gate series resistor of at least 5Ω will prevent the overshoot.

GND2 (Pin 2): Power Ground. High current spikes occur in this line when either GTDR1 or GTDR2 switches low.

GND1 (Pin 3): Analog Ground.

 C_{SET} (Pin 4): The capacitor from this pin to GND and R_{SET} determines oscillator frequency. The oscillator ramp is 5V and the frequency = 1.5/(R_{SET} C_{SET}).

PK_{LIM} (**Pin 5**): The threshold of the peak current limit comparator is GND. To set current limit, a resistor divider can be connected from V_{RFF} to current sense resistor.

 ${\sf CA_{OUT}}$ (Pin 6): This is the output of the current amplifier that senses and forces the line current to follow the reference signal that comes from the multiplier by commanding the pulse width modulator. When ${\sf CA_{OUT}}$ is low, the modulator has zero duty cycle.

I_{SENSE} (**Pin 7**): This is the inverting input of the current amplifier. This pin is clamped at –0.6V by an ESD protection diode.

M_{OUT} (**Pin 8**): This is the multiplier high impedance current output and the noninverting input of the current amplifier. This pin is clamped at –0.6V and 3V.

I_{AC} (Pin 9): This is the AC line voltage sensing input to the multiplier. It is a current input that is biased at 2V to minimize the crossover dead zone caused by low line voltage. At the pin, a 25k resistor is in series with the current input, so that a lowpass RC can be used to filter out the switching noise coming down from the line with a high line impedance environment.

VA_{OUT} (**Pin 10**): This is the output of the voltage error amplifier. The output is clamped at 13.5V. When the output goes below 2.5V, the multiplier output current is zero.

OVP (Pin 11): This is the input to the overvoltage comparator. The threshold is 1.05 times the reference voltage. When the comparator trips, the multiplier, which is quickly inhibited, blanks PFC switching to prevent further overshoot. This pin is also the input to the PWMOK comparator that releases the PWM soft start (SS2) after the PFC output gets close to the final voltage and has a hysteresis of approximately 150V for 382V PFC output.

 V_{REF} (Pin 12): This is the 7.5V reference. When V_{CC} goes low, V_{REF} will stay at 0V. V_{REF} biases most of the internal circuitry and can source up to 5mA externally.

V_{SENSE} (**Pin 14**): This is the inverting input to the voltage amplifier.





PIN FUNCTIONS (For application help with the PFC portion of this chip, see the LT1248 data sheet)

 R_{SET} (Pin 15): A resistor from R_{SET} to GND sets the oscillator charging current and the maximum multiplier output current which is used to limit the maximum line current.

 $I_{M(MAX)} = 3.75V/R_{SET}$

SS1 (Pin 16): Soft Start. SS1 is reset to zero for low V_{CC} . When V_{CC} rises above lockout threshold, SS1 is released to ramp up at a rate set by the internal $12\mu A$ current source and an external capacitor. During this ramp up, PFC reference voltage is equal to SS1 voltage. After SS1 rises past 7.5V, reference voltage remains at 7.5V.

 V_{CC} (Pin 17): This is the supply for the chip. The LT1509 has two fast gate drivers required to fast charge high power MOSFET gate capacitances. Good supply bypassing is required consisting of a 0.1μF ceramic capacitor in parallel with a low ESR electrolytic capacitor (56μF or higher) in close proximity to IC GND.

PWM SECTION

SS2 (Pin 13): PWM Soft Start. The comparator PWMOK monitors the OVP pin and releases the SS2 after the PFC output gets close to the final voltage.

 V_C (Pin 18): PWM current mode control voltage. Normally connects to the optocoupler amplifier output. A pull-up current of $50\mu A$ flows out of the pin.

RAMP (Pin 19): PWM current mode current sense input with current limit set to 1V.

GTDR2 (Pin 20): The PWM MOSFET gate driver is a 1.5A fast totem pole output. It is clamped at 15V. Capacitive loads like the MOSFET gates may cause overshoot. A gate series resistor of at least 5Ω will prevent the overshoot.

APPLICATIONS INFORMATION

Voltage Error Amplifier (PFC Section)

The voltage error amplifier has a 100dB DC gain and 3MHz unity-gain frequency. The output is internally clamped at 13.3V with V_{CC} = 18V. Maximum error amp output voltage decreases to V_{CC} – 1.5V for V_{CC} less than 12V. The noninverting input is tied to the 7.5V_{REF} through a diode and can be pulled down with the SS1 pin. Referring to Figure 1, V_{OUT} = V_{REF} [(R1 + R2)/R2]. With R1 = 1M and R2 = 20k, V_{OUT} = 382V. R1 through R4, C1 and C2 form the compensation for the voltage loop. Gain of the voltage error amp with the values shown is given by:

$$\frac{VA_{OUT}}{V_{OUT}} = -\frac{1 + j\frac{f}{1}}{(j)(f)(6.6)(1 + j\frac{f}{11})}$$

The small-signal gain for the remaining portion of the voltage loop for frequencies below the current loop bandwidth is (see Figure 2):

$$\frac{V_{OUT}}{VA_{OUT}} = \frac{V_{IN}}{(5\pi)(j)(f)(C_{OUT})(V_{OUT})} \sqrt{\frac{(R_{REF})(P_{IN})}{R_S(R_{IAC}+25k)}}$$

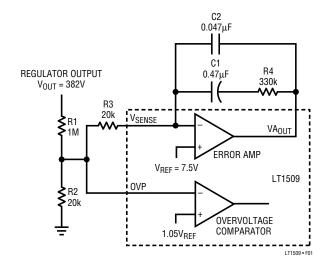


Figure 1

With V_{IN} = 120VAC, P_{IN} = 150W, R_S = 0.15 Ω , R_{REF} = 4k, R_{IAC} = 1M, V_{OUT} = 382V and C_{OUT} = 470 μ F, V_{OUT}/VA_{OUT} = 85/(j)(f). At very low frequencies, the loop has a -40dB/decade slope. Additional zero-pole compensation is added at 1Hz and 11Hz. The resulting loop gain and phase margin is shown in Figure 3. The unity-gain bandwidth is low compared to 120Hz, which results in low distortion and a high power factor.



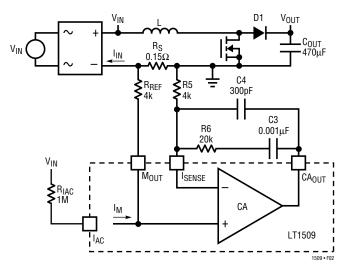


Figure 2

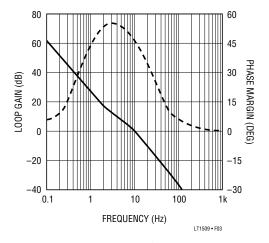


Figure 3

Current Amplifier (PFC Section)

The current amplifier has a 110dB DC gain, 3MHz unity-gain frequency and a $2V/\mu s$ slew rate. It is internally clamped at 8.5V. Note that in the current averaging operation, high gain at twice the line frequency is necessary to minimize line current distortion. Because CA_{OUT} may need to swing 5V over one line cycle at high line condition, 20mV AC will be needed at the inputs of the current amplifier for a gain of 260 at 120Hz. Especially at light load when the current loop reference signal is small, lower gain will distort the reference signal and line current. But, if signal gain at switching frequency is too high, the system behaves more like a current mode system and can cause subharmonic oscillation.

To avoid subharmonic oscillations, the amplified downslope of the inductor current must be less than the slope of the oscillator ramp.

$$\begin{split} &\frac{V_{CA(OUT)}}{V_{RS}} \leq \frac{(V_{OSC})(L)(f_{SW})}{(V_{OUT})(R_S)} \\ &= \frac{(5V)(500\mu\text{H})(100\text{k})}{(382V)(0.15\Omega)} = 4.4 \end{split}$$

If the current amplifier gain at 100kHz is less than 4.4, there will be no subharmonic oscillation. The open-loop gain of the current loop is given by:

$$\begin{split} &\frac{V_{RS}}{V_{CA(OUT)}} = \frac{(V_{OUT})(R_S)}{(j)(2\pi f)(L)(V_{OSC})} \\ &= \frac{(382V)(0.15\Omega)}{(j)(2\pi f)(500\mu H)(5V)} = \frac{3648}{(j)(f)} \end{split}$$

The current error amp, with R5 = 4k, R6 = 20k, C3 = $0.001\mu\text{F}$ and C4 = 300pF, provides zero pole compensation resulting in 16kHz loop crossover frequency. The current amp gain at 100kHz is 1.7. The resulting current loop gain and phase margin is shown in Figure 4.

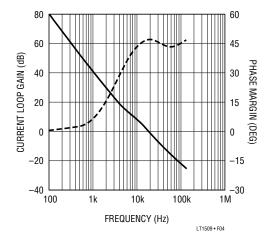


Figure 4

Multiplier

The multiplier has high noise immunity and superior linearity over its full operating range. The current gain is $I_M = (I_{AC}I_{EA}^2)/(200\mu A^2)$ with $I_{EA} = (VA_{OUT} - 2V)/25k$. The error amplifier output voltage required at the input to the multiplier is:

$$VA_{OUT} = 2 + \sqrt{\frac{(P_{IN})(R_S)(25)(R_{IAC} + 25k)}{(V_{IN}^2)(R_{REF})}}$$

See Figure 2 for R_{REF}.

VA_{OUT} is squared in the multiplier, resulting in excellent performance over a wide range of output power and input voltage without the addition of feedforward line frequency ripple. Care must be taken to avoid feeding switching frequency noise into the multiplier from the I_{AC} pin. An internal 25k is provided in series with the low impedance multiplier input so that only a capacitor from the I_{AC} pin to GND1 is required to filter noise. The maximum multiplier output current, which ultimately limits the input line current, is set by a resistor from the R_{SET} pin to GND1 according to the formula: $I_{M(MAX)} = 3.75V/R_{SET}$. Figure 5 shows I_{M} versus I_{AC} for various values of VA_{OUT}. Note that Figure 5 data was taken with $R_{SET} = 15k$.

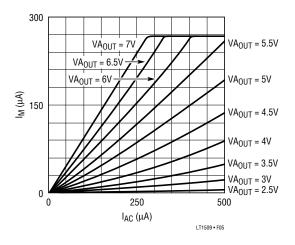


Figure 5. Multiplier Current I_M vs I_{AC} and VA_{OUT}

Oscillator Frequency and Maximum Line Current Setting

The oscillator frequency is set by R_{SET} and C_{SET} . R_{SET} is the resistor from the R_{SET} pin to GND1 and C_{SET} is the capacitor from the C_{SET} pin to GND1. R_{SET} should be determined first. The oscillator frequency, which is equal to the switching frequency for both the PFC and PWM section, is determined by:

$$f_{OSC} = \frac{1.5}{(R_{SET})(C_{SET})}$$

The multiplier output acts as the command signal to the current loop error amplifier. During steady-state operation the voltage across $R_{REF} = (I_M)(R_{REF}) = (I_{IN})(R_S)$. Based on this the value for R_S is determined by:

$$R_S \leq \frac{(I_{M(MAX)})(R_{REF})(V_{IN})(eff)}{P_{OUT}\sqrt{2}}$$

with R_{SET} = 15k, $I_{M(MAX)}$ = 3.75/15k = 250 μ A. For a 300W converter with an efficiency (eff) of 0.8 at low line (90V_{RMS}) and R_{REF} set to 4k, R_{S} should be less than:

$$\frac{(250\mu\text{A})(4\text{k})(90\text{VAC})(0.8)}{300\text{W}\sqrt{2}} = 0.169\Omega$$

A 0.15Ω resistor will yield a maximum peak input current of $(I_{M(MAX)})(R_{REF}/R_S)=(250\mu A)(4k)/0.15\Omega=6.67A$. For a 100kHz switching frequency with $R_{SET}=15k$, $C_{SET}=1.5/(100kHz)(15k)=1$ nF. For added protection the LT1509 provides a second independent current limit comparator. When the input voltage to the comparator (PK_{LIM} pin) dips below 0V, GTDR1 pin quickly goes low turning off the PFC power switch. A resistor divider from V_{REF} to R_S (Figure 6) senses the voltage across the line current sense resistor (R_S) and limits the peak input line current to [(7.5V/R1) + $50\mu A$] (R2/R_S). The $50\mu A$ represents the PK_{LIM} input current which flows out of the PK_{LIM} pin. With R1 = 10k and R2 = 1.8k, I_{IN} = 9.6A peak above the 6.67A peak average plus the input inductor peak ripple current.

Always use R_{SET} to set the primary line current limit. The PK_{LIM} comparator is only for secondary protection. When the line current reaches the primary limit, V_{OUT} can no longer be supported with the given input current and begins to fall. System stability is maintained by the current loop which is controlled by the current amplifier. When the

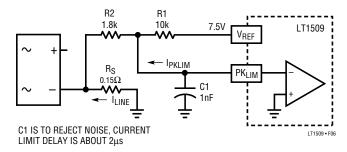


Figure 6



line current reaches the secondary limit, the comparator takes over control and hysteresis may occur causing audible noise.

Overvoltage Protection (PFC Section)

Because of the slow loop response necessary for power factor correction, output overshoot can occur following a sudden load reduction or removal. To protect downstream components, the LT1509 provides an overvoltage comparator which senses the output voltage and quickly reduces the line current demand. Referring back to Figure 1, V_{OUT} is 382V and during normal operation, since no current flows in R3, 7.5V appears at both the V_{SENSE} and OVP pins. When V_{OUT} overshoots its preset value, the overcurrent from R1 will flow through R2 as well as R3. The voltage amplifier feedback will keep V_{SENSE} at 7.5V. Therefore, the equivalent AC resistance seen by the OVP pin is R2 in parallel with R3 or 10k. With these values and the overvoltage comparator trip level internally set at $1.05V_{REF}$, the comparator trips when V_{OUT} overshoots 10%. Overvoltage trip level is given by:

$$(\%)V_{OUT} = 5\% \left(\frac{R2 + R3}{R3}\right)$$

For additional protection, the OVP pin can be connected to V_{OUT} through an independent resistor divider (see Figure 7). This ensures overvoltage protection during safety agency abnormal testing conditions, such as opening R1 or shorting R2.

The output of the multiplier looks like a high impedance current source. In the current loop, offset line current is determined by multiplier offset current and input offset voltage of the current error amplifier. A -4mV current amplifier V_{OS} translates to 27mA line current and 6.7W input power for 250VAC line if a 0.15Ω sense resistor is used. Under a no-load condition or when the load power is less than the offset output power, the offset line current could slowly charge the output to an overvoltage level. This is because the best the overvoltage comparator can do is to reduce the multiplier output current to zero. Unfortunately, this does not guarantee zero output current if the current amplifier has offset. To regulate V_{OUT} under

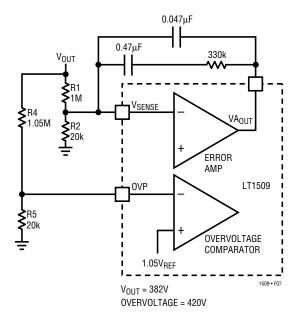


Figure 7

this condition, the amplifier M1 (see Block Diagram) becomes active. When VA_{OUT} reduces to 2.2V, M1 supplies up to $7\mu A$ of current to the resistor at the I_{SENSE} pin in order to cancel a negative V_{OS} and keep V_{OUT} error to within 2V.

Undervoltage Lockouts and Soft Start

The LT1509 turns on when V_{CC} reaches 16V and remains on until V_{CC} falls below 10V, whereupon the chip enters the lockout state. In the lockout state, the oscillator is off and the V_{RFF} and gate driver pins remain low. A capacitor from SS1 to GND1 determines the ramp-up time of the PFC section. SS1 is released from a zero when V_{CC} rises above the lockout threshold. Once released, an internal 14µA current source ramps the voltage error amplifier's reference voltage to 7.5V. SS1 voltage then continues beyond 7.5V. A second capacitor from SS2 to GND1 determines the start-up time from the PWM section. A PWMOK comparator (see Block Diagram) holds SS2 low until the OVP pin reaches 7V. This corresponds to the PFC output voltage reaching approximately 93% of its preset voltage. SS2 is diode coupled to the PMW comparator which is connected to the V_C pin by a second diode. Holding SS2 low at any time will disable PWM output. Once released, the 14µA current source ramps the PWM comparator



input up to $V_{\mathbb{C}}$ and then the SS2 voltage continues beyond $V_{\mathbb{C}}$. The PWMOK comparator contains hysteresis and will pull SS2 low disabling the PWM section if the PFC output voltage falls below approximately 62% of its preset value (240V with nominal 382V output).

Start Up and Supply Voltage

The LT1509 draws only 250 μ A before the chip starts at 16V on V_{CC}. To trickle start, a 91k resistor from the power line to V_{CC} supplies trickle current, and C4 holds V_{CC} up while switching starts (see Figure 8); then the auxiliary winding takes over and supplies the operating current. Note that D3 and the larger values of C3 are only necessary for systems that have sudden large load variations down to minimum load and/or very light load conditions. Under these conditions the loop may exhibit a start/restart mode because switching remains off long enough for C4 to discharge below 10V. Large values for C3 will hold V_{CC} up until switching resumes. For less severe load variations D3 is replaced with a short and C3 is omitted. The turns ratio between the primary winding determines V_{CC} according to :

$$\frac{V_{OUT}}{V_{CC} - 2V} = \frac{N_P}{N_S}$$

for 382V V_{OUT} and 18V V_{CC} , Np/Ns \approx 19.

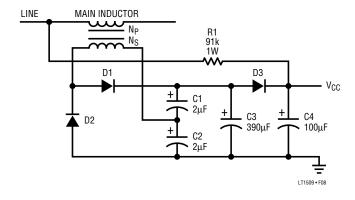


Figure 8

Output Capacitor (PFC Section)

GTDR2 (PWM) pulse is synchronized to GTDR1 (PFC) pulse with 53% duty cycle delay to reduce RMS ripple current in the output capacitor. See PFC/PWM Synchronization graph in the Typical Performance Characteristics section.

The peak-to-peak 120Hz PFC output ripple is determined by:

$$V_{P-P} = 2I_{LOAD(DC)}(Z)$$

where $I_{LOAD(DC)}$ is the DC load current of the PWM stage and Z is the capacitor impedance at 120Hz.

For $470\mu\text{F}$, impedance is 2.8Ω at 120Hz. At 335W load, $I_{LOAD(DC)} = 335\text{V}/382\text{V} = 0.88\text{A}$, $V_{P-P} = (2)(0.88)(2.8\Omega) = 5\text{V}$. If less ripple is desired higher capacitance should be used. The selection of the output capacitor is based on voltage ripple, hold-up time and ripple current. Assuming the DC converter (PWM section) is designed to operate with 240V to 382V_{IN} , the minimum hold-up time is a function of the energy storage capacity of the capacitor:

$$t_{HOLD} = \frac{(0.5)C_{OUT}}{P_{OUT}} \left[(382V - 0.5V_{P-P})^2 - 240V^2 \right]$$

with $C_{OUT}=470\mu F$, $V_{P-P}=11.5V$, and $P_{OUT}=335W$, $t_{HOLD}=60ms$ which is 3.6 line cycles at 60Hz. The ripple current can be divided into two major components. The first is the 120Hz component which is related to the DC load current as follows:

$$I_{120HZ} \approx I_{LOAD(DC)} \sqrt{2}$$

The second component is made up of switching frequency components due to the PFC stage charging the capacitor and the PWM stage discharging the capacitor. For a 300W output PFC forward converter running from an input voltage of $100V_{RMS}$, the total high frequency ripple current was measured to be $1.79A_{RMS}$.

For the United Chemicon KMH 450V capacitor series, ripple current at 100kHz is specified 1.43 times higher than the 120Hz limit.



The total equivalent 120Hz ripple in the output capacitor can be calculated by:

$$I_{RMS} = \sqrt{I_{120HZ}^2 + \left(\frac{I_{HF}}{1.43}\right)^2}$$

I_{HF} = 100kHz Ripple Current.

For $I_{LOAD(DC)} = 0.88A$, $1_{120Hz} = 0.62A$ and the equivalent 120Hz ripple current is:

$$I_{RMS} = \sqrt{0.62^2 + \left(\frac{1.79}{1.43}\right)^2} = 1.4A_{RMS}$$

Table 1 lists the ripple current components from lab measurements for various output powers and line voltages. The 120Hz ripple current rating at 105°C ambient is 1.72A for the 470 μ F KMH 35mm \times 50mm capacitor. The expected life of the output capacitor may be calculated from thermal stress analysis:

$$L = (L_0) 2^{\left[\frac{(105^{\circ}\text{C} + \Delta T_K) - (T_A + \Delta T_0)}{10}\right]}$$

where

L = Expected life time

 L_0 = Hours of load life at rated ripple current and rated ambient temperature

 ΔT_K = Capacitor internal temperature rise at rated condition. ΔT_K = (I²R)/(KA), where I is the rated current, R is capacitor ESR and KA is a volume constant.

T_A = Operating ambient temperature

 ΔT_0 = Capacitor internal temperature rise at operating condition

Table 1. PFC Capacitor RMS Ripple Current

	100W		200W		30	0W
V _{INRMS}	I _{120HZ}	I _{HF}	I _{120HZ}	I _{HF}	I _{120HZ}	I _{HF}
100	0.2	0.6	0.41	1.18	0.62	1.79
120	0.2	0.5	0.41	0.97	0.62	1.45
230	0.2	0.53	0.41	0.87	0.62	1.26

In our example, L_0 = 2000 hours assuming ΔT_K = 5°C at rated 1.72A. ΔT_0 can then be calculated from:

$$\Delta T_0 = \Delta T_K \left(\frac{I_{RMS}}{1.72A} \right)^2 = 5^{\circ} C \left(\frac{1.4A}{1.72A} \right)^2 = 3.3^{\circ} C$$

Assuming the operating ambient temperature is 60°C, the approximate lifetime is:

$$L = (2000)(2)^{\left[\frac{(105^{\circ}C + 5^{\circ}C) - (60 + 3.3^{\circ}C)}{10}\right]}$$

= 50,870 Hours

For longer life a capacitor with a higher ripple current rating or parallel capacitors should be used.

PWM Comparators

The LT1509 includes two comparators in the PWM section which implement peak current mode control. The primary current sense voltage is fed into the RAMP pin. The V_{C} or Control Voltage pin sets the primary peak current level. An additional current limit comparator turns GTDR2 off in the event the RAMP pin voltage exceeds 1V. Referring to the Block Diagram, there is a 1.2V offset between the RAMP and V_{C} pin. This feature simplifies the connection to an optocoupler because the V_{C} pin no longer has to be pulled all the way to ground to inhibit switching. On-chip blanking avoids reset due to leading edge noise.

Typical Application

Figure 9 shows a 24VDC, 300W power factor corrected, universal input supply. The 2-transistor forward converter offers many benefits including low peak currents, nondissipative snubber, 500VDC switches and automatic core reset guaranteed by the LT1509's 50% maximum duty cycle.



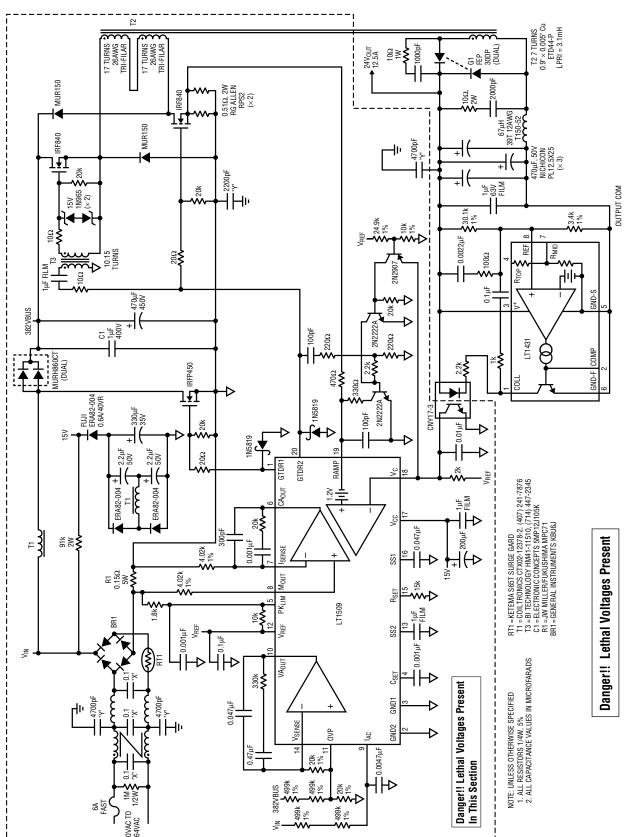


Figure 9. 24V, 300W Off-Line PFC Supply

An LT1431 reference/amplifier coupled to a low cost optoisolator closes the loop from secondary side to primary side. Unity loop frequency is a conservative 3kHz. Figure 10 shows the output voltage's response with a 2A to almost 10A current step. Output voltage is maintained to within 0.5V during the load step. Efficiency versus power and line voltage is shown in Figure 11. The PFC preregulator alone has efficiency numbers between 90% and 97% over line and load.

A 3-turn secondary added to the 70-turn primary of T1 bootstraps V_{CC} to about 15V supplying the chip's 13mA requirement as well as about 39mA to cover the gate current of the three FETs and high side transformer. A 0.15 Ω sense resistor is used to sense input current and servo to the command created by the outer voltage and multiplier. Thus the input current follows the input line

voltage, and changes as necessary, in order to maintain constant bank voltage. The forward converter sees a voltage input of 382VDC unless the line voltage drops out, in which case the $470\mu\text{F}$ main capacitor discharges to 240VDC before the PWM stage is shut down. Compared to a typical off-line converter, the effective input voltage range of the forward converter is much smaller, simplifying the design. Additionally, the higher bus voltage provides greater hold-up times for given capacitor size.

Because the high side transformer effectively delays the turn-on reverse recovery spike past the end of the built-in blanking time, an external blanking transistor is needed. Controlling the output current during an output short circuit depends on the duty cycle reducing to a small fraction of steady state. An additional transistor disables blanking during turn-on and output short circuit.

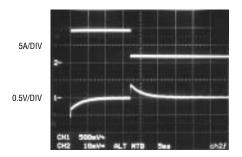


Figure 10

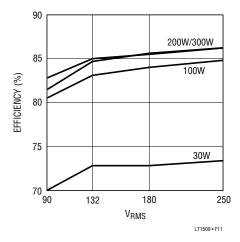


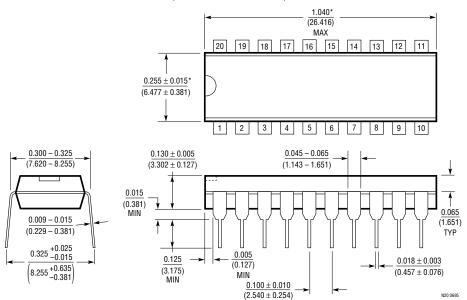
Figure 11

PACKAGE DESCRIPTION

Dimension in inches (millimeters) unless otherwise noted.

N Package 20-Lead PDIP (Narrow 0.300)

(LTC DWG # 05-08-1510)

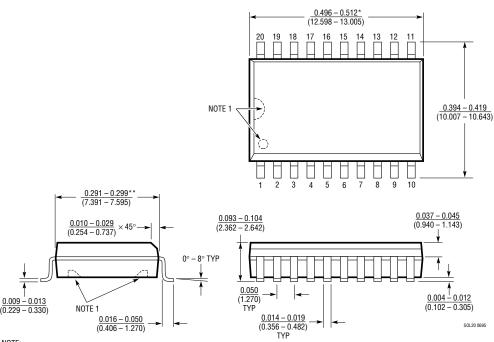


*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.

MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

SW Package 20-Lead Plastic Small Outline (Wide 0.300)

(LTC DWG # 05-08-1620)



NOTE:

- 1. PIN 1 IDENT, NOTCH ON TOP AND CAVITIES ON THE BOTTOM OF PACKAGES ARE THE MANUFACTURING OPTIONS. THE PART MAY BE SUPPLIED WITH OR WITHOUT ANY OF THE OPTIONS.
- *DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE

^{**}DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE



LT1509

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1084	5A Low Dropout Linear Regulator	Good for Post Regulation of Switching Power Supplies
LT1105	Simplified Off-Line Controller	Solution for Universal Off-Line Inputs with Output to 100W
LT1241-5	High Frequency Current Mode PWM Controller	Operates at Oscillator Frequencies up to 500kHz
LT1247	High Frequency Current Mode PWM Controller	Operates at Oscillator Frequencies up to 1MHz
LT1248	Full-Feature Average Current Mode Power Factor Controller	Provides All Features in 16-Lead Package
LT1249	Minimal Parts Count Power Factor Controller	Simplified PFC Design
LT1508	Power Factor and PWM Controller	Voltage Mode PWM